



Micro Commercial Components 20736 Marilla Street Chatsworth

CA 91311

Phone: (818) 701-4933 Fax: (818) 701-4939 **SI2302**

Features

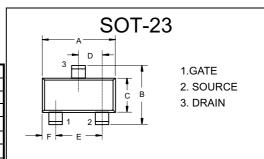
- 20V,3.0A, $R_{DS(ON)}$ =55m Ω @ V_{GS} =4.5V $R_{DS(ON)}$ =82m Ω @ V_{GS} =2.5V
- High dense cell design for extremely low R_{DS(ON)}
- Rugged and reliable
- Lead free product is acquired
- SOT-23 Package
- Marking Code: S2 Epoxy meets UL 94 V-0 flammability rating

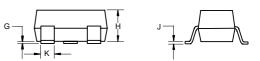
Moisture Sensitivity Level 1

Maximum Ratings @ 25°C Unless Otherwise Specified

Symbol	Parameter	Rating	Unit
V_{DS}	Drain-source Voltage	20	V
I _D	Drain Current-Continuous	3	Α
I _{DM}	Drain Current-Pulsed ^a	10	Α
V_{GS}	Gate-source Voltage	±8	V
P _D	Total Power Dissipation	1.25	W
R _{+JA}	Thermal Resistance Junction to Ambient ^b	100	°C/W
TJ	Operating Junction Temperature	-55 to +150	$^{\circ}$
T _{STG}	Storage Temperature	-55 to +150	$^{\circ}\mathbb{C}$

N-Channel Enhancement Mode Field Effect Transistor



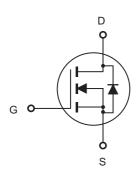


DIMENSIONS					
	INCHES		MM		
DIM	MIN	MAX	MIN	MAX	NOTE
Α	.110	.120	2.80	3.04	
В	.083	.104	2.10	2.64	
С	.047	.055	1.20	1.40	
D	.035	.041	.89	1.03	
Е	.070	.081	1.78	2.05	
F	.018	.024	.45	.60	
G	.0005	.0039	.013	.100	
Η	.035	.044	.89	1.12	
J	.003	.007	.085	.180	
K	015	020	37	51	

Suggested Solder

Pad Layout inches mm

Internal Block Diagram





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Electrical Characteristics T_A = 25°C unless otherwise noted

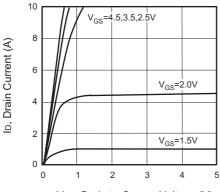
Parameter	Symbol	Test Condition	Min	Тур	Max	Units
Off Characteristics						
Drain-Source Breakdown Voltage	BV _{DSS}	$V_{GS} = 0V, I_{D} = 10\mu A$	20			V
Zero Gate Voltage Drain Current	I _{DSS}	V _{DS} = 20V, V _{GS} = 0V			1	μA
Gate Body Leakage Current, Forward	I _{GSSF}	$V_{GS} = 8V, V_{DS} = 0V$			100	nA
Gate Body Leakage Current, Reverse	Igssr	V_{GS} = -8V, V_{DS} = 0V			-100	nA
On Characteristics °						
Gate Threshold Voltage	V _{GS(th)}	$V_{GS} = V_{DS}$, $I_D = 50\mu A$	0.65		1.2	V
Static Drain-Source		$V_{GS} = 4.5V, I_{D} = 3.6A$		55	72	mΩ
On-Resistance	R _{DS(on)}	$V_{GS} = 2.5V, I_D = 3.1A$		82	110	mΩ
Forwand Transconductance	9 _{FS}	$V_{DS} = 5V, I_{D} = 3.6A$		8.5		S
Dynamic Characteristics d						
Input Capacitance	C _{iss}			237		pF
Output Capacitance	C _{oss}	$V_{DS} = 10V, V_{GS} = 0V,$ f = 1.0 MHz		120		pF
Reverse Transfer Capacitance	C _{rss}]		45		pF
Switching Characteristics d						
Turn-On Delay Time	t _{d(on)}			23	45	ns
Turn-On Rise Time	t _r	$V_{DD} = 10V, I_D = 3.6A,$		11	30	ns
Turn-Off Delay Time	t _{d(off)}	$V_{GS} = 4.5V$, $R_{GEN} = 6\Omega$		34	70	ns
Turn-On Fall Time	t _f			36	70	ns
Total Gate Charge	Q_g $V_{DS} = 10V, I_D = 3.6A,$ $V_{GS} = 4.5V$			6	10	nC
Gate-Source Charge				1.4		nC
Gate-Drain Charge	Q _{gd}	- VGS 1.0V		1.8		nC
Drain-Source Diode Characteristics an	d Maximun F	Ratings				
Drain-Source Diode Forward Current b	Is				0.94	Α
Drain-Source Diode Forward Voltage °	V _{SD}	$V_{GS} = 0V, I_{S} = 0.94A$			1.2	V

Notes:

a.Repetitive Rating: Pulse width limited by maximum junction temperature.
b.Surface Mounted on FR4 Board, t ≤ 10 sec.
c.Pulse Test: Pulse Width ≤ 300µs, Duty Cycle ≤ 2%.
d.Guaranteed by design, not subject to production testing.



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VDS, Drain-to-Source Voltage (V)

Figure 1. Output Characteristics

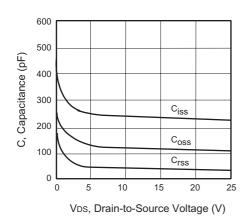


Figure 3. Capacitance

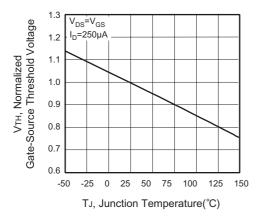
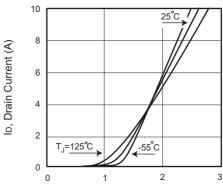


Figure 5. Gate Threshold Variation with Temperature



Vgs, Gate-to-Source Voltage (V)

Figure 2. Transfer Characteristics

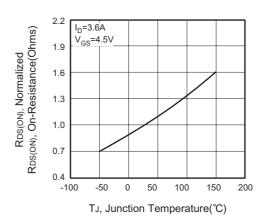


Figure 4. On-Resistance Variation with Temperature

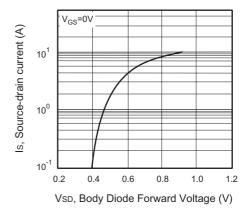


Figure 6. Body Diode Forward Voltage Variation with Source Current



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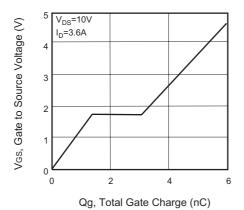


Figure 7. Gate Charge

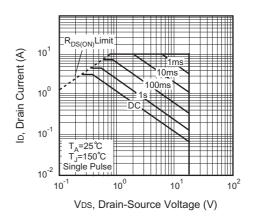


Figure 8. Maximum Safe Operating Area

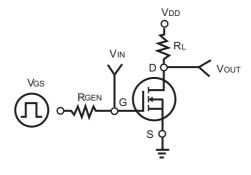


Figure 9. Switching Test Circuit

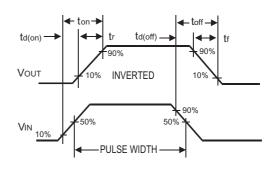


Figure 10. Switching Waveforms

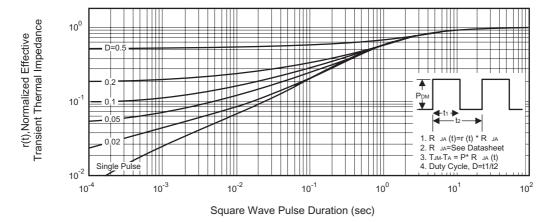


Figure 11. Normalized Thermal Transient Impedance Curve



Ordering Information:

Device	Packing
Part Number-TP	Tape&Reel: 3Kpcs/Reel

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